MAX.

800E

800

4

25

UNIT

V

А

A

### Three quadrant triacs guaranteed commutation

### BTA204 series D, E and F

MAX.

600D

600E

600F

600

4

25

### **GENERAL DESCRIPTION**

Passivated guaranteed commutation triacs in a plastic envelope, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

### **PINNING - TO220AB**

# 

current

QUICK REFERENCE DATA

PARAMETER

Repetitive peak

off-state voltages RMS on-state current

Non-repetitive peak on-state

SYMBOL

 $V_{DRM}$ 

I<sub>T(RMS)</sub>

**PIN CONFIGURATION** 

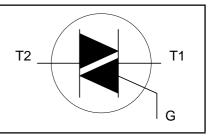
 $I_{TSM}$ 



**BTA204-**

**BTA204-**

BTA204-



| PIN | DESCRIPTION     |  |  |
|-----|-----------------|--|--|
| 1   | main terminal 1 |  |  |
| 2   | main terminal 2 |  |  |
| 3   | gate            |  |  |
| tab | main terminal 2 |  |  |

### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL   | PARAMETER   | CONDITIONS   | MIN.     | M                               | UNIT               |             |
|--|---|--|----------|---------------------------------|--------------------|-------------|
| V <sub>DRM</sub>   | Repetitive peak off-state voltages  |  | -        | <b>-600</b><br>600 <sup>1</sup> | <b>-800</b><br>800 | V           |
| I <sub>T(RMS)</sub>                                      | RMS on-state current  | full sine wave;<br>T <sub>mb</sub> ≤ 107 °C<br>full sine wave; | -        |                                 | A                  |             |
| I <sub>TSM</sub>   | on-state current  | $T_j = 25$ °C prior to<br>surge<br>t = 20 ms<br>t = 16.7 ms    | -        |                                 | 25<br>27           | A           |
| l²t<br>dl <sub>⊤</sub> /dt                               | I <sup>2</sup> t for fusing<br>Repetitive rate of rise of<br>on-state current after<br>triggering |  | -        | 3                               | 8.1<br>00          | A²s<br>A/μs |
| I <sub>GM</sub><br>P <sub>GM</sub><br>P <sub>G(AV)</sub> | Peak gate current<br>Peak gate power<br>Average gate power  | over any 20 ms   |          |                                 | 2<br>5<br>).5      | A<br>W<br>W |
| T <sub>stg</sub><br>T <sub>j</sub>                       | Storage temperature<br>Operating junction<br>temperature  |  | -40<br>- |                                 | 50<br>25           | °C<br>°C    |

**<sup>1</sup>** Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6  $A/\mu s$ .

## Three quadrant triacs guaranteed commutation

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### THERMAL RESISTANCES

| SYMBOL                                      | PARAMETER  | CONDITIONS                              | MIN. | TYP.         | MAX.            | UNIT              |
|---|--|---|------|--------------|-----------------|-------------------|
| R <sub>th j-mb</sub><br>R <sub>th j-a</sub> | Thermal resistance<br>junction to mounting base<br>Thermal resistance<br>junction to ambient | full cycle<br>half cycle<br>in free air |      | -<br>-<br>60 | 3.0<br>3.7<br>- | K/W<br>K/W<br>K/W |

### STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

| SYMBOL          | PARAMETER                                | CONDITIONS  | MIN.           | TYP.              |             | MAX.            |          | UNIT        |
|-----------------|--|---|----------------|-------------------|-------------|-----------------|----------|-------------|
|                 |  | BTA204-   |                |                   | D           | E               | F        |             |
| I <sub>GT</sub> | Gate trigger current <sup>2</sup>        | V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A<br>T2+ G+                           | _              | _                 | 5           | 10              | 25       | mA          |
|                 |  | T2+ G-  | -              | -                 | 5<br>5<br>5 | 10              | 25       | mA          |
| .               | Latabing ourrant                         | T2- G-<br>V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A                          | -              | -                 | 5           | 10              | 25       | mA          |
| I <sub>L</sub>  | Latching current                         | $V_D = 12 V, I_{GT} = 0.1 A$<br>T2+G+<br>T2+G-                                    | -              | -                 | 6<br>9      | 12<br>18        | 20<br>30 | mA<br>mA    |
| I <sub>H</sub>  | Holding current                          | T2- G-<br>V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A                          | -              | -                 | 6<br>6      | 12<br>12        | 20<br>20 | mA<br>mA    |
| $V_{T} V_{GT}$  | On-state voltage<br>Gate trigger voltage | $I_{T} = 5 A$<br>$V_{D} = 12 V; I_{T} = 0.1 A$<br>$V_{D} = 400 V; I_{T} = 0.1 A;$ | -<br>-<br>0.25 | 1.4<br>0.7<br>0.4 |             | 1.7<br>1.5<br>- |          | V<br>V<br>V |
| I <sub>D</sub>  | Off-state leakage current                | $T_{j} = 125 \ ^{\circ}C$<br>$V_{D} = V_{DRM(max)};$<br>$T_{j} = 125 \ ^{\circ}C$ | -              | 0.1               |             | 0.5             |          | mA          |

### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

| SYMBOL                | PARAMETER   | CONDITIONS  |     | MIN. |     | TYP. | MAX. | UNIT |
|-----------------------|---|---|-----|------|-----|------|------|------|
|                       |   | BTA204-   | D   | E    | F   |      |      |      |
| dV <sub>D</sub> /dt   | Critical rate of rise of off-state voltage        | $V_{DM} = 67\% V_{DRM(max)};$<br>$T_j = 125 °C; exponential waveform; gate open circuit$  | 20  | 30   | 50  | -    | -    | V/µs |
| dl <sub>com</sub> /dt | Critical rate of change of commutating current    | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 ^{\circ}\text{C};$<br>$I_{T(RMS)} = 4 \text{ A};$<br>$dV_{com}/dt = 20V/\mu s; \text{ gate}$<br>open circuit           | 1.0 | 2.0  | 2.5 | -    | -    | A/ms |
| dl <sub>com</sub> /dt | Critical rate of change of<br>commutating current | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C};$<br>$I_{T(RMS)} = 4 \text{ A};$<br>$dV_{com}/dt = 0.1 \text{ V}/\mu\text{s}; \text{ gate}$<br>open circuit | 5.0 | -    | -   | -    | -    | A/ms |
| t <sub>gt</sub>       | Gate controlled turn-on time                      | $I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$<br>$I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}$  | -   | -    | -   | 2    | -    | μs   |

**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

8

7

6

5

4

3

2

1 0

0

1000

100

25

20

15

10

5

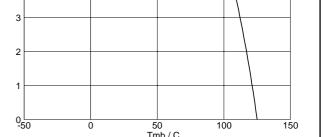
01

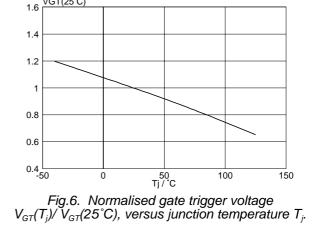
BTA204 series D, E and F

### Three quadrant triacs guaranteed commutation

#### Tmb(max) / C Ptot / W IT(RMS) / A 5 104 107℃ ⊂ = 180 107 120 110 90 3 60 113 30 2 116 119 122 125 0<u></u>\_50 50 Tmb / C 100 2 3 IT(RMS) / A 3 4 5 0 150 Fig.1. Maximum on-state dissipation, $P_{tot}$ , versus rms on-state current, $I_{T(RMS)}$ , where $\alpha$ = conduction angle. Fig.4. Maximum permissible rms current $I_{T(RMS)}$ , versus mounting base temperature $T_{mb}$ . 12 |T(RMS) / A 10 tim 8 6 dl<sub>T</sub>/dt limit G+ quadrant 2 10 **∟** 10us 100us 10ms 1ms T/s 100ms 8.01 0.1 10 surge duration / s Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 107^{\circ}$ C. Fig.2. Maximum permissible non-repetitive peak on-state current $I_{TSM}$ , versus pulse width $t_p$ , for sinusoidal currents, $t_p \le 20ms$ . 30 | ITSM / A VGT(Tj VGT(25 1.6 ITSM 1.4 Ti initial = 25 C max 1.2 1 0.8 0.6 10 100 Number of cycles at 50Hz 1000 100 150 0

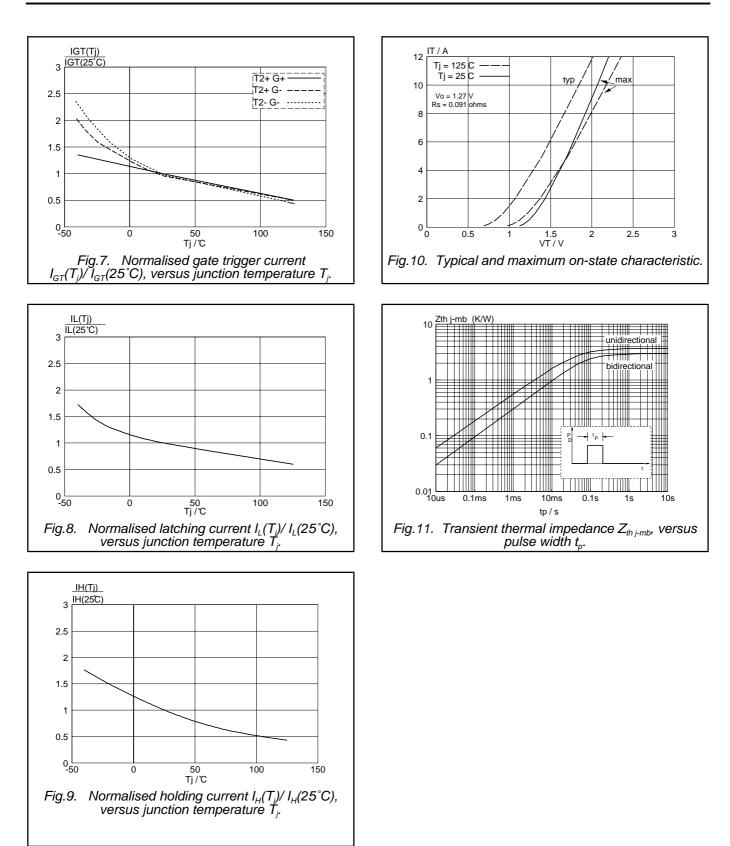
Fig.3. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus number of cycles, for sinusoidal currents, f = 50 Hz.





BTA204 series D, E and F

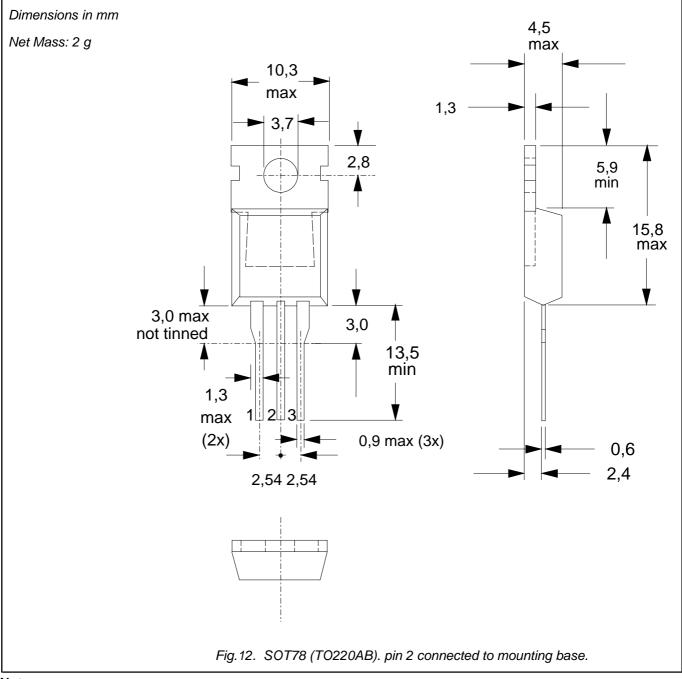
### Three quadrant triacs guaranteed commutation



### Three quadrant triacs guaranteed commutation

### BTA204 series D, E and F

### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for SOT78 (TO220) envelopes.
 Epoxy meets UL94 V0 at 1/8".

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#### DEFINITIONS

| DATA SHEET STATUS                 |                    |   |  |  |  |  |
|-----------------------------------|--------------------|---|--|--|--|--|
| DATA SHEET<br>STATUS <sup>3</sup> | PRODUCT<br>STATUS⁴ | DEFINITIONS   |  |  |  |  |
| Objective data                    | Development        | This data sheet contains data from the objective specification for<br>product development. Philips Semiconductors reserves the right to<br>change the specification in any manner without notice  |  |  |  |  |
| Preliminary data                  | Qualification      | This data sheet contains data from the preliminary specification.<br>Supplementary data will be published at a later date. Philips<br>Semiconductors reserves the right to change the specification without<br>notice, in order to improve the design and supply the best possible<br>product                                     |  |  |  |  |
| Product data                      | Production         | This data sheet contains data from the product specification. Philips<br>Semiconductors reserves the right to make changes at any time in<br>order to improve the design, manufacturing and supply. Changes will<br>be communicated according to the Customer Product/Process<br>Change Notification (CPCN) procedure SNW-SQ-650A |  |  |  |  |

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

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<sup>3</sup> Please consult the most recently issued datasheet before initiating or completing a design.

**<sup>4</sup>** The product status of the device(s) described in this datasheet may have changed since this datasheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.